- Operation from Very Slow Edges
- Improved Line-Receiving Characteristics
- High Noise Immunity

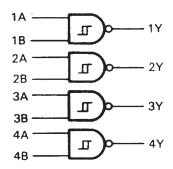
description

Each circuit functions as a 2-input NAND gate, but because of the Schmitt action, it has different input threshold levels for positive (V_{T+}) and for negative going (V_{T-}) signals.

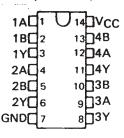
These circuits are temperature-compensated and can be triggered from the slowest of input ramps and still give clear, jitter-free output signals.

The SN54132, SN54LS132, and SN54S132 are characterized for operation over the full military temperature range of -55°C to 125°C. The SN74132, SN74LS132, and SN74S132 are characterized for operation from 0°C to 70°C.

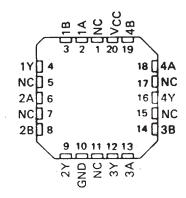
logic diagram (positive logic)



SN54132, SN54LS132, SN54S132 . . . J OR W PACKAGE SN74132 . . . N PACKAGE SN74LS132, SN74S132 . . . D OR N PACKAGE (TOP VIEW)

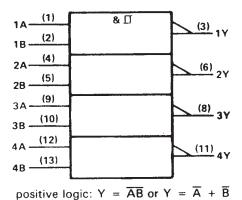


SN54LS132, SN54S132 . . . FK PACKAGE (TOP VIEW)



NC-No internal connection

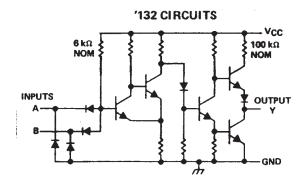
logic symbol†



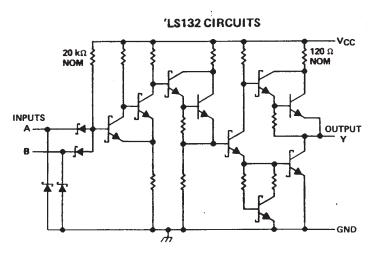
[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, N, and W packages.

schematics



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'S132 CIRCUITS VCC 50 \(\Omega \) NOM OUTPUT B GND

Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note	(1)	7 V
Input voltage: '132, 'S132		5.5 V
Operating free-air temperature:	: SN54'	. — 55°C to 125°C
	SN74'	0°C to 70°C
Storage temperature range		. – 65°C to 150°C

NOTE 1: Voltages values are with respect to network ground terminal.



recommended operating conditions

		SN5413	2		SN7413	2	UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
IOH High-level output current			- 0.8			- 0.8	mA
IOL Low-level output current			16			16	mA
TA Operating free-air temperature	- 55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDI	rions†		MIN	TYP#	MAX	UNIT
V _{T+}	V _{CC} = 5 V				1.5	1.7	2	V
V _T -	V _{CC} = 5 V				0.6	0.9	1.1	V
V _{hys} (V _{T+} -V _{T-})	V _{CC} = 5 V	•			0.4	0.8		٧
ViK	V _{CC} = MIN,	I _I = - 12 mA					- 1.5	V
Voн	V _{CC} = MIN,	V ₁ = 0.6 V,	1 _{OH} = - 0.8 mA		2.4	3.4		V
VOL	V _{CC} = MIN,	V ₁ = 2 V,	IOL = 16 mA			0.2	0.4	V
I _{T+}	V _{CC} = 5 V,	V ₁ = V _{T+}			-	- 0.43		mΑ
1 _T _	V _{CC} = 5 V,	Λ1 = Λ ^L			-	- 0.56		mA
l ₁	V _{CC} = MAX,	V ₁ = 5.5 V					1	mA
ΊΗ	V _{CC} = MAX,	V ₁ = 2.4 V					40	μА
ΊL	V _{CC} = MAX,	V _{1L} = 0.4 V				- 0.8	- 1,2	mA
los§	V _{CC} = MAX			-	- 18		- 55	mA
ГССН	V _{CC} = MAX					15	24	mA
ICCL	V _{CC} = MAX				Ţ	26	40	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$ (see figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CON	DITIONS	MIN	TYP	MAX	UNIT
tPLH	Anv		$R_1 = 400 \Omega$.	C ₁ = 15 pF		15	22	ns
tPHL	Any	,	ML = 400 32,	C[- 15 pr		15	22	ns

[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$. § Not more than one output should be shorted at a time.

SN54LS132, SN74LS132 QUADRUPLE 2-INPUT POSITIVE-NAND SCHMITT TRIGGERS

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recommended operating conditions

		S	SN54LS132			SN74LS132		
		MIN	NOM	MAX	MIN	MOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
ЮН	High-level output current			- 0.4			-0.4	mA
IOL	Low-level output current		***	4			8	mA
TA	Operating free-air temperature	- 55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	т,	ST CONDIT	rougt	S	N54LS1	32	SI	UNIT		
PANAMETER		ST CONDIT	IUNS'	MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
V _{T+}	V _{CC} = 5 V			1.4	1.6	1.9	1.4	1.6	1.9	V
V _T	V _{CC} = 5 V			0.5	0.8	1	0.5	8.0	1	V
∨ _{hγs} (∨ _{T +} ~∨ _{T ~})	V _{CC} = 5 V		.	0.4	0.8		0.4	0.8		V
VIK	VCC = MIN, II =	– 18 mA				- 1.5			- 1.5	V
Voн	V _{CC} = MIN, V _I	= 0.5 V,	IOH = - 0.4 mA	2.5	3.4		2.7	3.4		٧
Voi	V _{CC} = MIN, V _I	= 1.9 V	IOL = 4 mA		0.25	0.4		0.25	0.4	V
VOL	ACC - MIIA' A	- 1.5 V	IOL = 8 mA					0.35	0.5	
IT+	V _{CC} = 5 V, V _I	= V _{T+}			- 0.14		-	- 0.14		mA
1 _T	V _{CC} = 5 V, V _i	= V _T _		-	- 0.18			- 0.18		mA
l _l	VCC = MAX, VI	= 7 V				0.1			0.1	mA
ЧН	V _{CC} = MAX, V ₁	= 2.7 V				20			20	μА
IL	V _{CC} = MAX, V _I	L = 0.4 V				- 0.4			- 0.4	mA
os §	V _{CC} = MAX			- 20		- 100	- 20		- 100	mA
¹ ссн	V _{CC} = MAX				5.9	11		5.9	11	mA
¹ CCL	V _{CC} = MAX				8.2	14		8.2	14	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$ (see figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CON	IDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Anv		$R_1 = 2 k\Omega$	C ₁ = 15 pF		15	22	ns
^t PHL		'	" = 2 K32,	OF - 19 bi-		15	22	ns

[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ} \text{ C}$.

[§] Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second

recommended operating conditions

			SN54S1	32		SN74S1	32	UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT	
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V	
Іон	High-level output current			– 1			– 1	mA	
IOL	Low-level output current			20			20	mA	
TA	Operating free-air temperature	– 55		125	0		70	°C	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDIT	novet		SN54S1	32	:	UNIT		
PARAMETER		TEST CONDIT	TONS	MIN	TYP‡	MAX	MIN	TYP‡	MAX	ONT
V _{T+}	V _{CC} = 5 V			1.6	1.77	1.9	1.6	1.77	1.9	V
V _T _	V _{CC} = 5 V			1.1	1.22	1.4	1.1	1.22	1.4	V
V _{hys} (V _{T+} - V _{T-})	V _{CC} = 5 V			0.2	0.55		0.2	0.55		٧
VIK	V _{CC} = MIN,	I ₁ = - 18 mA				- 1.2			- 1.2	٧
VOH	VCC = MIN,	V ₁ = 1.1 V,	IOH = - 1 mA	2.5	3.4		2.7	3.4		V
VOL	V _{CC} = MIN,	V ₁ = 1.9 V,	I _{OL} = 20 mA			0.5			0.5	٧
IT+	V _{CC} = 5 V,	V1 = VT+			- 0.9			- 0.9		mA
1T_	V _{CC} = 5 V,	V _I = V _T _			- 1.1			- 1.1		mA
l ₁	V _{CC} = MAX,	V _I = 5.5 V				1			1	mA
ЧН	V _{CC} = MAX,	V ₁ = 2.7 V				50			50	μΑ
116	V _{CC} = MAX,	V _{IL} = 0.5 V				- 2			- 2	mΑ
los§	V _{CC} = MAX			- 40		- 100	– 40		– 100	mA
¹ CCH	V _{CC} = MAX				28	44		28	44	mA
ICCL	V _{CC} = MAX				44	68		44	68	mA

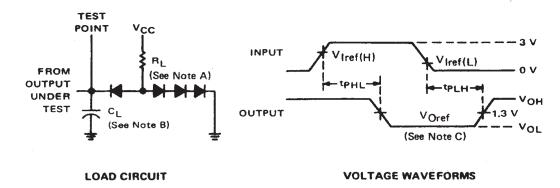
 $^{^\}dagger$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$ (see figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CON	DITIONS	MIN T	YP MA	UNIT
^t PLH	A or B	~	$R_1 = 280 \Omega_s$	C ₁ = 15 pF		7 10.	5 ns
^t PHL	A 01 B		ME - 200 16,	O[- 13 pr	8	3.5 1	3 ns

[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ} \text{C}$. § Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. All diodes are 1N3064 or equivalent.

B. C_L includes probe and jig capacitance.

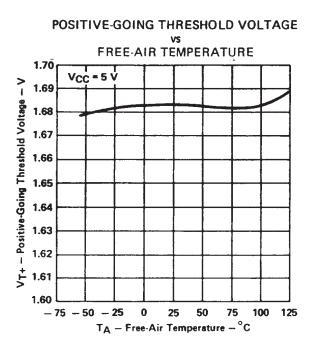
C. Generator characteristics and reference voltages are:

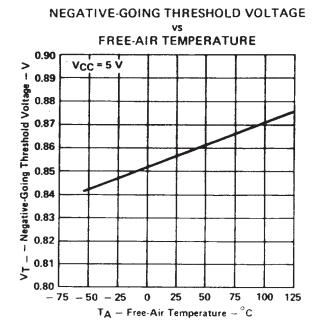
	G	enerator C	haracteris	tics	Reference Voltages				
	Zout	PRR	tr	tf	VI ref(H)	VI ref(L)	VO ref		
SN54'/SN74'	50	1 MHz	10 ns	10 ns	1.7 V	0.9 V	1.5 V		
SN54LS'/SN74LS'	50	1 MHz	15 ns	6 ns	1.6 V	0.8 V	1.3 V		
'S132	50	1 MHz	2.5 ns	2.5 ns	1.8 V	1.2 V	1.5 V		

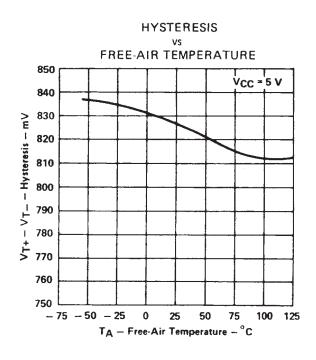
FIGURE 1

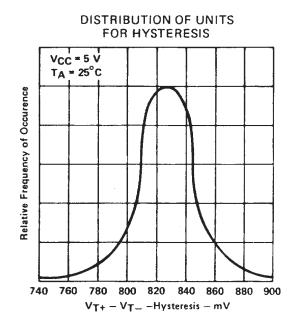


TYPICAL CHARACTERISTICS OF '132 CIRCUITS

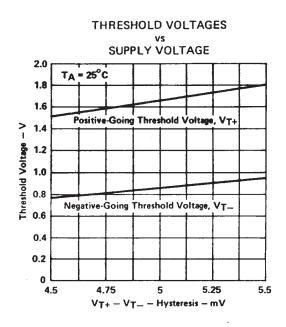


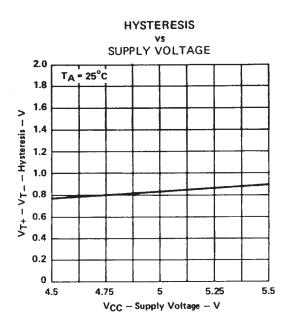


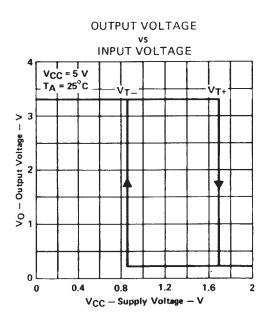




TYPICAL CHARACTERISTICS OF '132 CIRCUITS





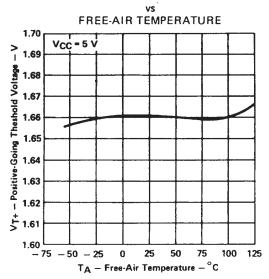


 $^{^{\}dagger}$ Data for temperatures below 0° C and 70° C and supply below 4.75 V and above 5.25 V are applicable for SN54132 only.

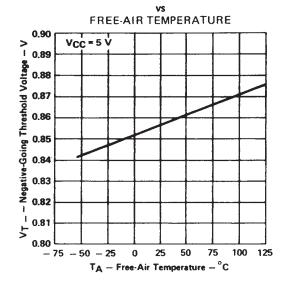


TYPICAL CHARACTERISTICS OF 'LS132 CIRCUITS

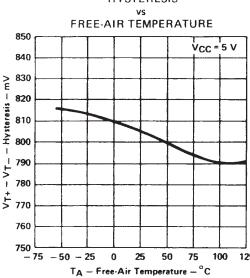
POSITIVE-GOING THRESHOLD VOLTAGE



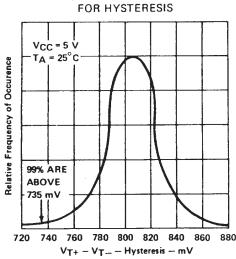
NEGATIVE-GOING THRESHOLD VOLTAGE



HYSTERESIS

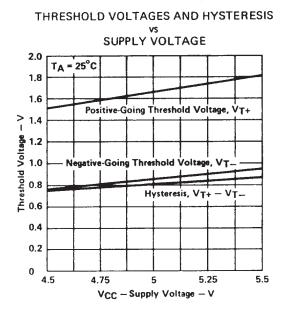


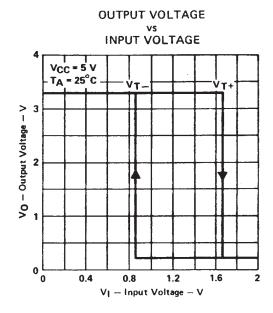
DISTRIBUTION OF UNITS



Data for temperatures below 0°C and above 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS132 only.

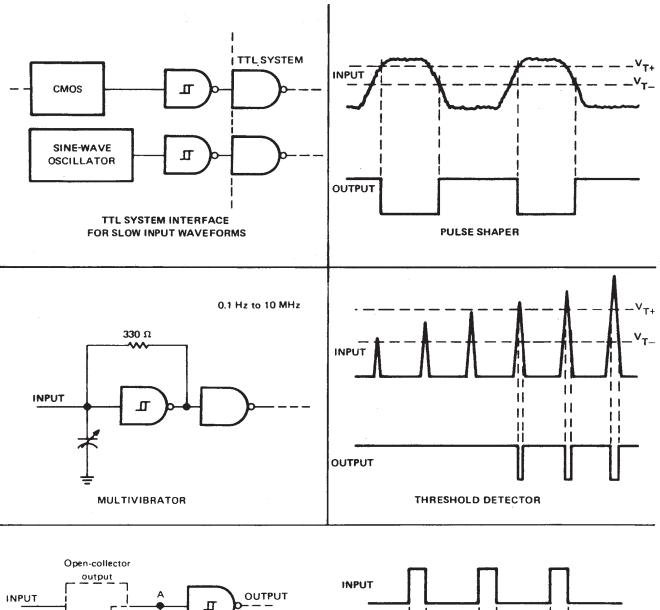
TYPICAL CHARACTERISTICS OF 'LS132 CIRCUITS

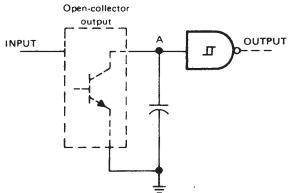


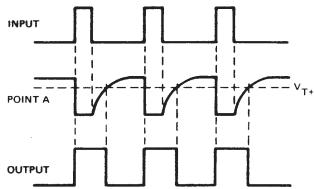


[†] Data for temperatures below 0°C and above 70°C and supply voltages below 4.75 V and above 5.25 V are applicable for SN54LS132 only.

TYPICAL APPLICATION DATA







PULSE STRETCHER



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